

**GAUTENG DEPARTMENT OF EDUCATION /
GAUTENGSE DEPARTEMENT VAN ONDERWYS
SENIOR CERTIFICATE EXAMINATION /
SENIORSERTIFIKAAT-EKSAMEN**

**TECHNIKA (ELECTRONICS) SG /
TECHNIKA (ELEKTRONIES) SG**

QUESTION 1 / VRAAG 1

$$1.1.1 \quad X_{L1} = 2\pi FL_1 = 2\pi 50 \times 100 \text{ H} = 31,41\Omega$$

$$X_{C1} = \frac{1}{2\pi FC_1} = 63,66 \Omega$$

$$R_1 = 100 \Omega$$

$$I_R = \frac{V_T}{R_L} = \frac{100}{100} = 1 \text{ amp}$$

$$I_L = \frac{V_T}{X_{L1}} = \frac{100}{31,41} = 3,18 \text{ amp}$$

$$I_C = \frac{V_T}{X_{C1}} = \frac{100}{63,66} = 1,57 \text{ amp}$$

(17)

$$\begin{aligned} 1.1.2 \quad I_T &= \sqrt{I_R^2 + (I_L - I_C)^2} \\ &= \sqrt{(1)^2 + (3,18 - 1,57)^2} \\ &= \sqrt{1^2 + 1,61^2} \\ &= \sqrt{1^2 + 2,59} \\ &= \sqrt{3,59} \\ &= 1,9 \text{ amp} \end{aligned}$$

(3)

$$\begin{aligned}
 1.1.3 \quad Z &= \frac{VT}{IT} \\
 &= \frac{100}{1,9} \\
 &= 52,63\Omega
 \end{aligned}
 \tag{3}$$

$$\begin{aligned}
 1.2 \quad X_{L1} &= 2\pi FL_1 = 2 \times \pi \times 88\,000 \times 0,15 \times 10^{-6} = 0,0829\ \Omega \\
 X_{L2} &= 2\pi FL_2 = 2 \times \pi \times 98\,000 \times 0,15 \times 10^{-6} = 0,0892\ \Omega
 \end{aligned}$$

$$X_C = \frac{1}{2\pi FC}$$

$$X_C = 2\pi FC = 1$$

$$X_C = X_L \text{ resoneer}$$

$$C = \frac{1}{2\pi FX_C}$$

$$\begin{aligned}
 \therefore C_1 &= \frac{1}{2 \times \pi \times 88\,000 \times 0,0829} \\
 &= 21,8\ \mu\text{F}
 \end{aligned}$$

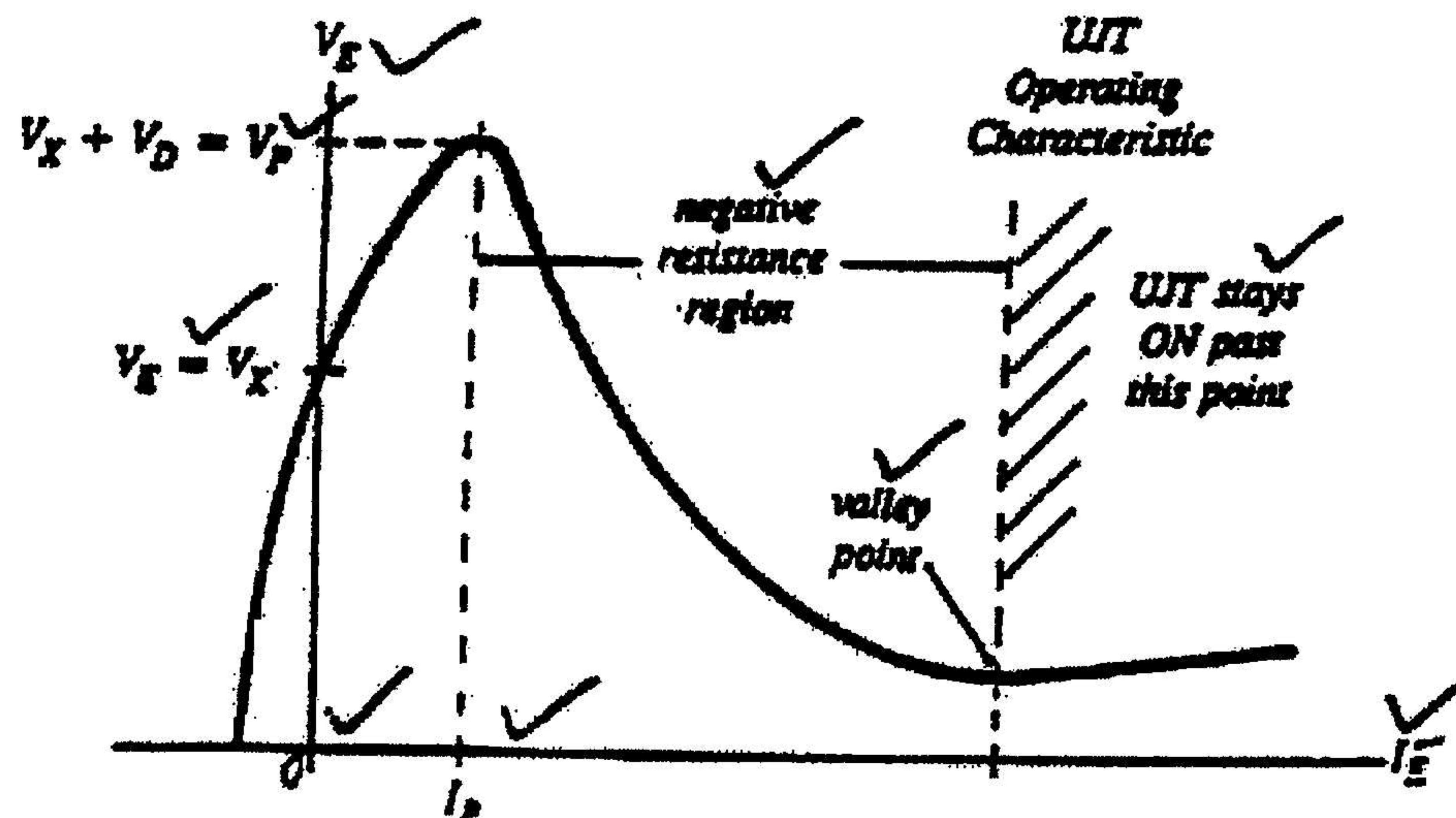
$$\begin{aligned}
 C_2 &= \frac{1}{2\pi FX_{C_2}} \\
 &= \frac{1}{2 \times \pi \times 98\,000 \times 0,0924} \\
 &= 17,57\ \mu\text{F}
 \end{aligned}$$

The range must be between 21,8 μF and 17,57 μF

QUESTION 2 / VRAAG 2

- | | | |
|-------|------------------------------|-----|
| 2.1.1 | 680 k Ω resistor | (3) |
| 2.1.2 | NPN Transistor | (2) |
| 2.1.3 | 0,01 μF Capacitor | (2) |
| 2.1.4 | Diode | (2) |
| 2.1.5 | PNP Transistor | (2) |

2.2

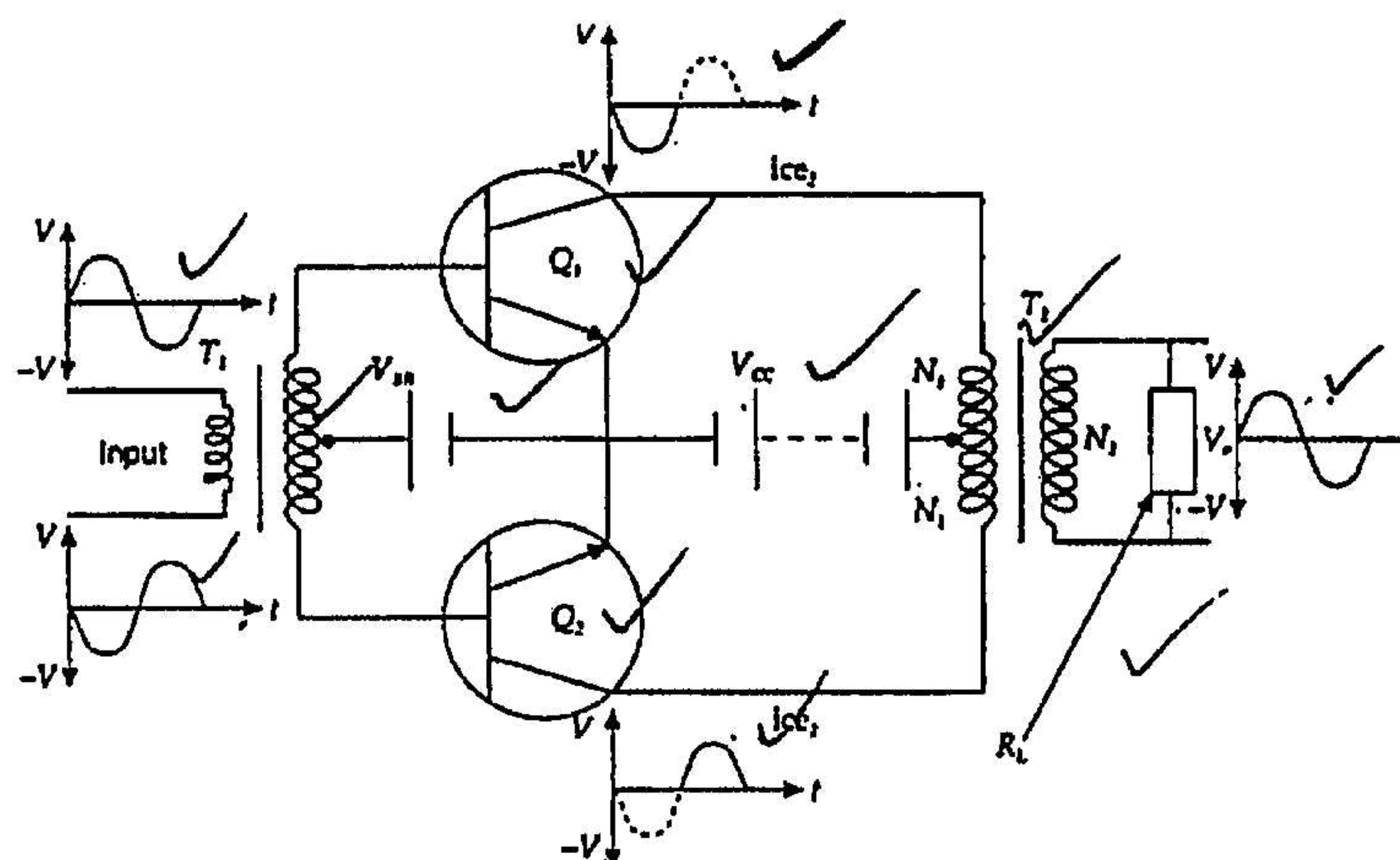
**MAIN OPERATING POINTS:**

1. With V_E at 0 V, the diode D is reverse-biased because of the high voltage at point V_x in the bar. A small leakage current flows through the diode in the reverse direction. This is shown in the graph as a "negative" current flow.
2. As V_E slowly increases, the diode D remains reverse-biased, but the leakage current falls. This condition holds until V_E reaches a voltage equal to V_x in the bar. At this point the voltages at each end of the diode are equal and no current flows in either direction.
3. As V_E rises above V_x , the diode is still not forward-biased, and a small forward current flows. (15)
4. When V_E reaches a point equal to V_x plus the diode voltage (0,6V), the conditions rapidly change. This point is called the peak voltage point V_p .

- 2.3 Light dimming circuits
Speed-control circuits (2)

QUESTION 3

3.1



PUSH-PULL AMPLIFIER / BALANSVERSTERKER

OPERATION:

Transistors Q1 and Q2 conduct when their bases become positive with respect to their emitters.

Thus the transistors conduct one half cycle at a time.

The centre-tapped output transformer combines the two half-cycles to produce one complete cycle.

V_{bb} serves as the biasing voltage.

V_{cc} serves as the supply voltage.

Has a fixed gain.

WERKING:

Transistors Q1 en Q2 gelei wanneer hul onderskeie basisse positief word ten opsigte van hul emitters.

Die transistors gelei dus een halfsiklus om die beurt.

Die middeltap-uitsettransformator kombineer die twee halfsiklusse om sodoende een volledige uitset-sein te lewer

V_{bb} dien as voorspanning vir die transistors.

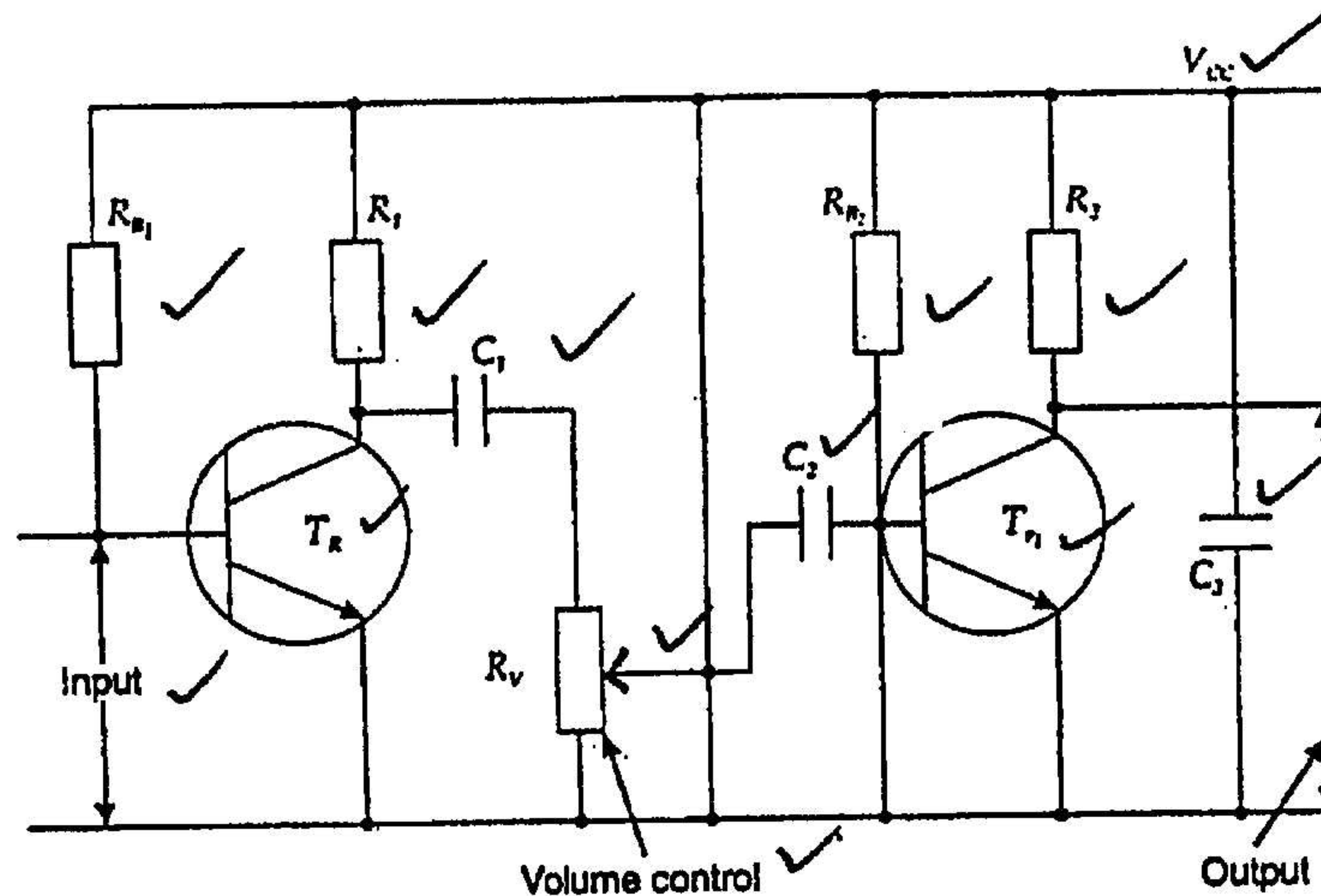
V_{cc} dien as die toevoerspanning.

Het 'n konstante wins.

(20)

OR

3.1



RADIO-FREQUENCY AMPLIFIER / RADIOFREKWENSIE-VERSTERKER

OPERATION:

Gain may be changed continuously.

Variable resistor (volume control) is used to change the gain.

Adjustment does not influence the DC bias.

All of the signal current is developed across R_v .

When the slider of R_v is moved upwards, a bigger AC signal voltage will appear between the earth and the conductor, which is fed to the input of T_2 and amplified.

WERKING:

Die wins mag voortdurend verander word.

Die verstelbare weerstand (volume-beheer) word gebruik om die wins te verander.

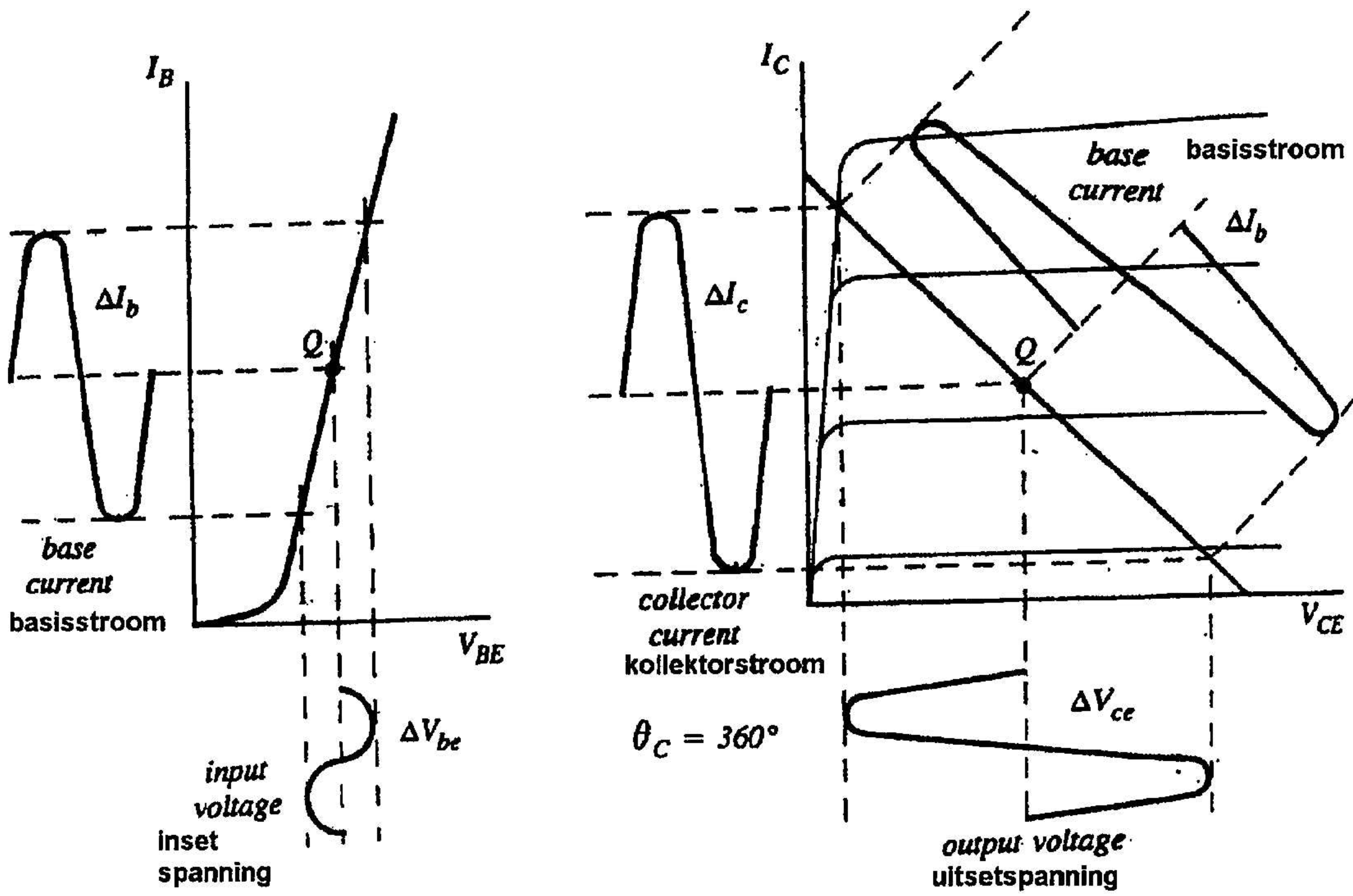
Enige verstelling beïnvloed nie die GS-voorspanning van die transistor nie.

Die totale seinstroom ontwikkel oor R_v .

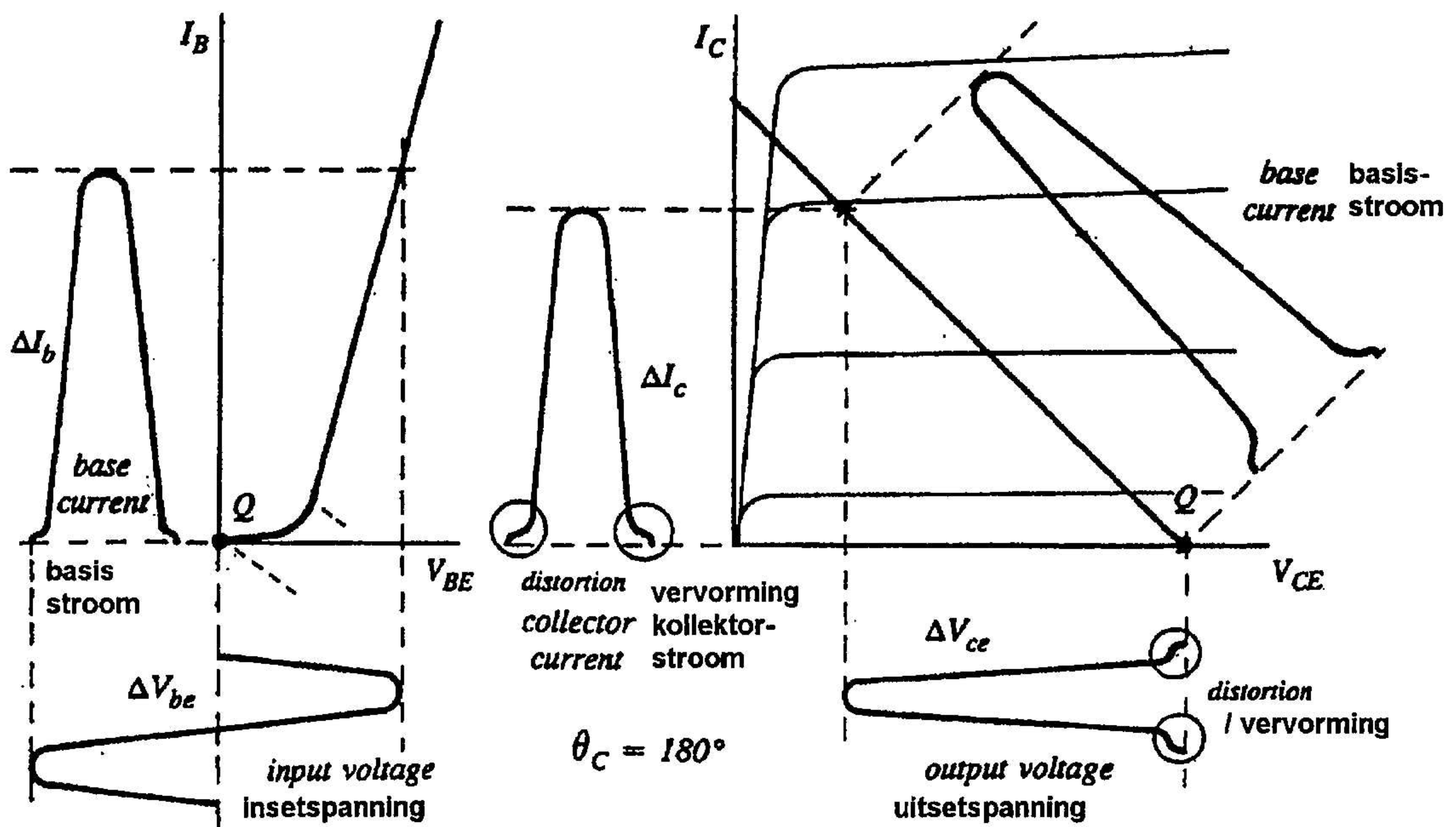
Wanneer die gleyer van die verstelbare weerstand opwaarts beweeg word, sal dit 'n groter ws-seinspanning tussen die aarde en die geleier tot gevolg hê wat na transistor T_2 se inset gevoer word en versterk word.

(20)

3.2



Class A biased Transistor (Mid-point Biased) which produces a Maximum Un-distorted Output



A Pure Class B Biased Transistor

(10)

3.3 Negative feedback

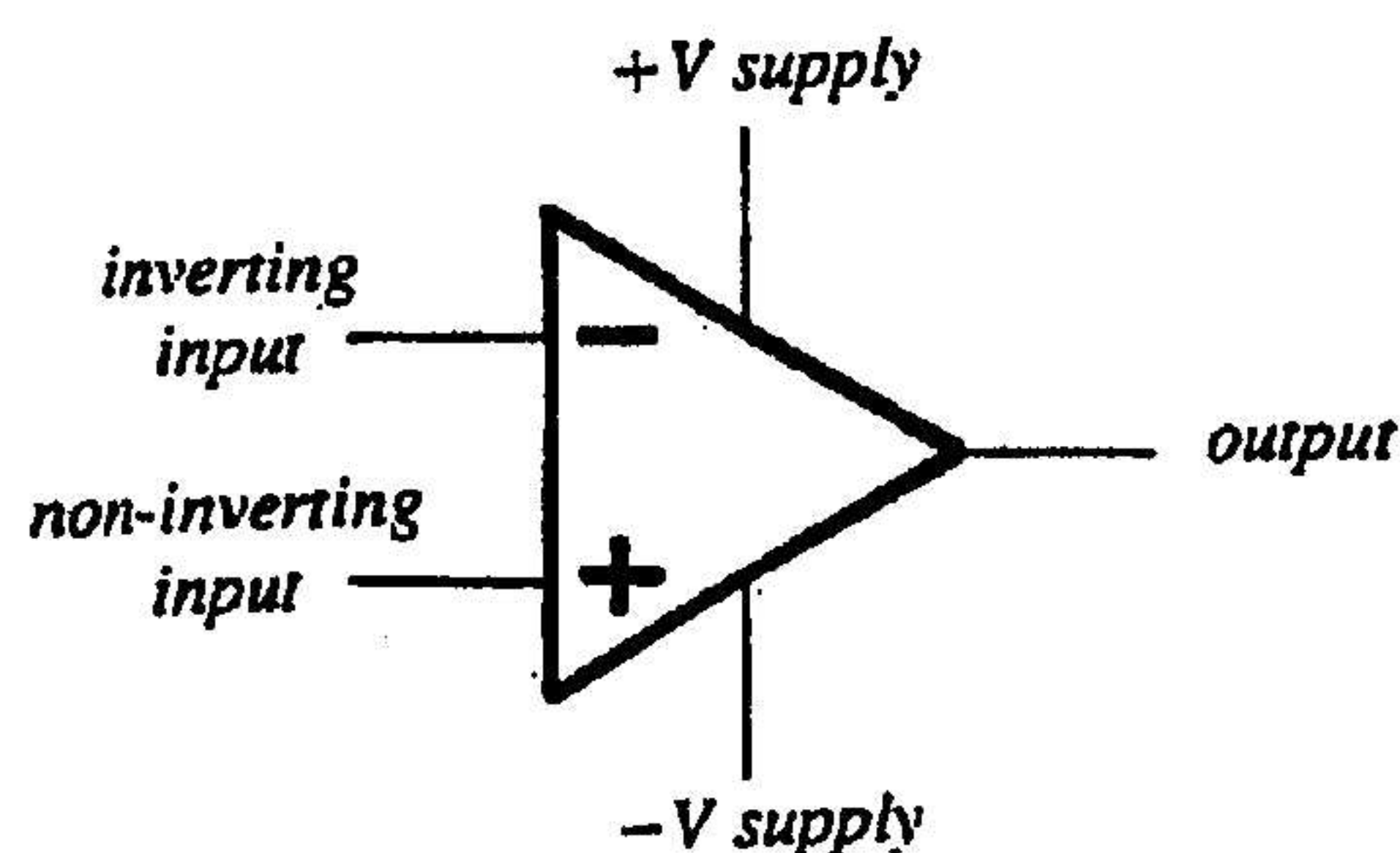
- Output is 180° out of Phase with input
- Result in gain is unity OR less than maximum gain. – Gain is effectively reduced.
- More stable ITO gain & temperature
- Less noise.
- Broader band width

3.4 The characteristics of an “ideal” OP AMP are:

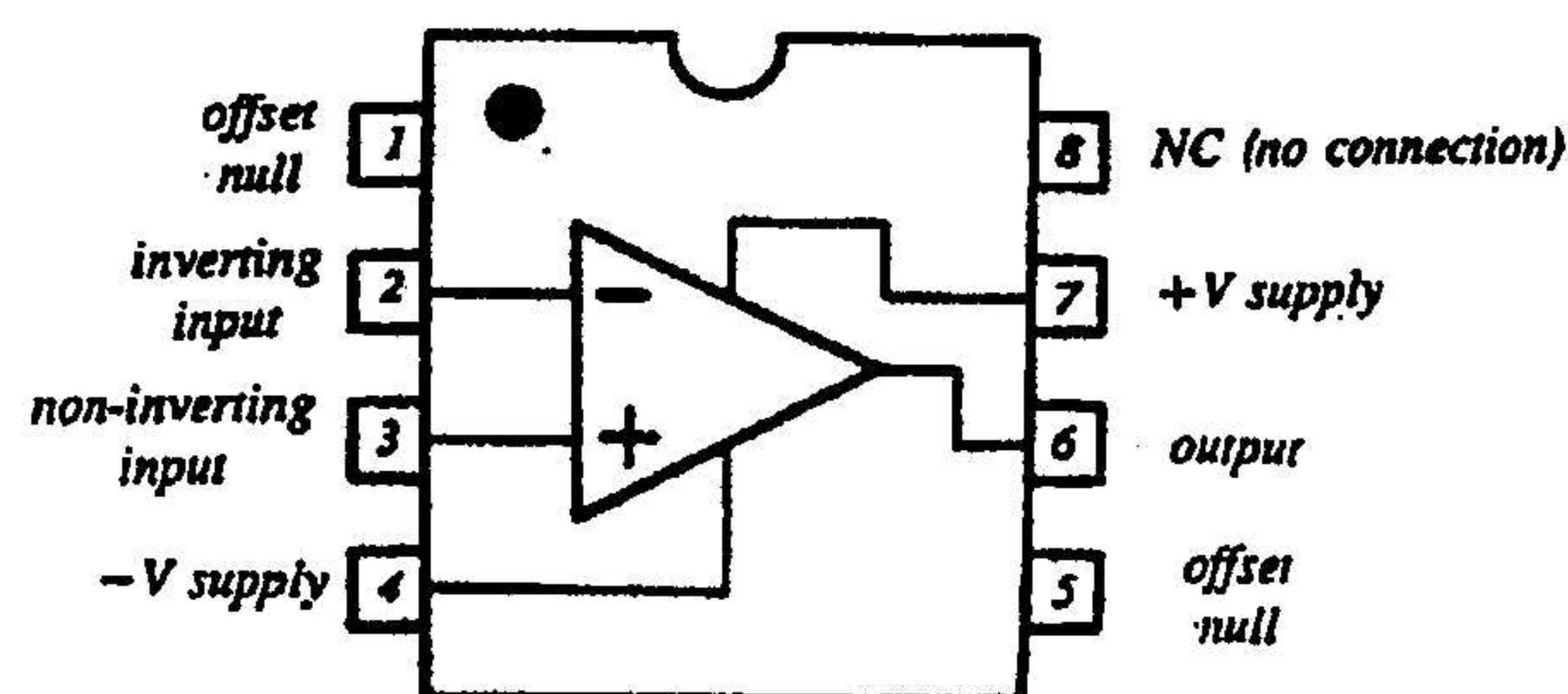
1. $A_v \approx \alpha$: infinite open loop voltage gain (they have more gain than necessary which can be sacrificed using feedback and in turn improve a number of other properties).
2. $Z_{in} \approx \alpha$: infinite input impedance (Z_{in}) (this will not “load down” a high -impedance signal source).
3. $Z_{out} \approx 0$: zero output impedance (Z_{out}) (they are able to deliver a signal to a low-impedance source).
4. Bandwidth $\approx \alpha$: infinite bandwidth.
5. unconditionally stable
6. differential inputs (ie : two inputs).
7. Common-mode rejection (this gives them the ability to reduce hum and noise).

(5)

3.5



Operational Amplifier
Circuit Symbol



(5)

$$3.6 \quad V_x = V_{out} \times \frac{R_2}{R_1 + R_2}$$

$$V_x = 4V$$

$$V_{out} = ?$$

$$R_1 = R_F = 250 \times 10^3 \Omega$$

$$R_2 = R_{in} = 50 \times 10^3 \Omega$$

$$V_x = V_{out} \times \frac{R_2}{R_1 + R_2}$$

$$V_{out} = V_x \times \frac{50000}{250000 + 50000}$$

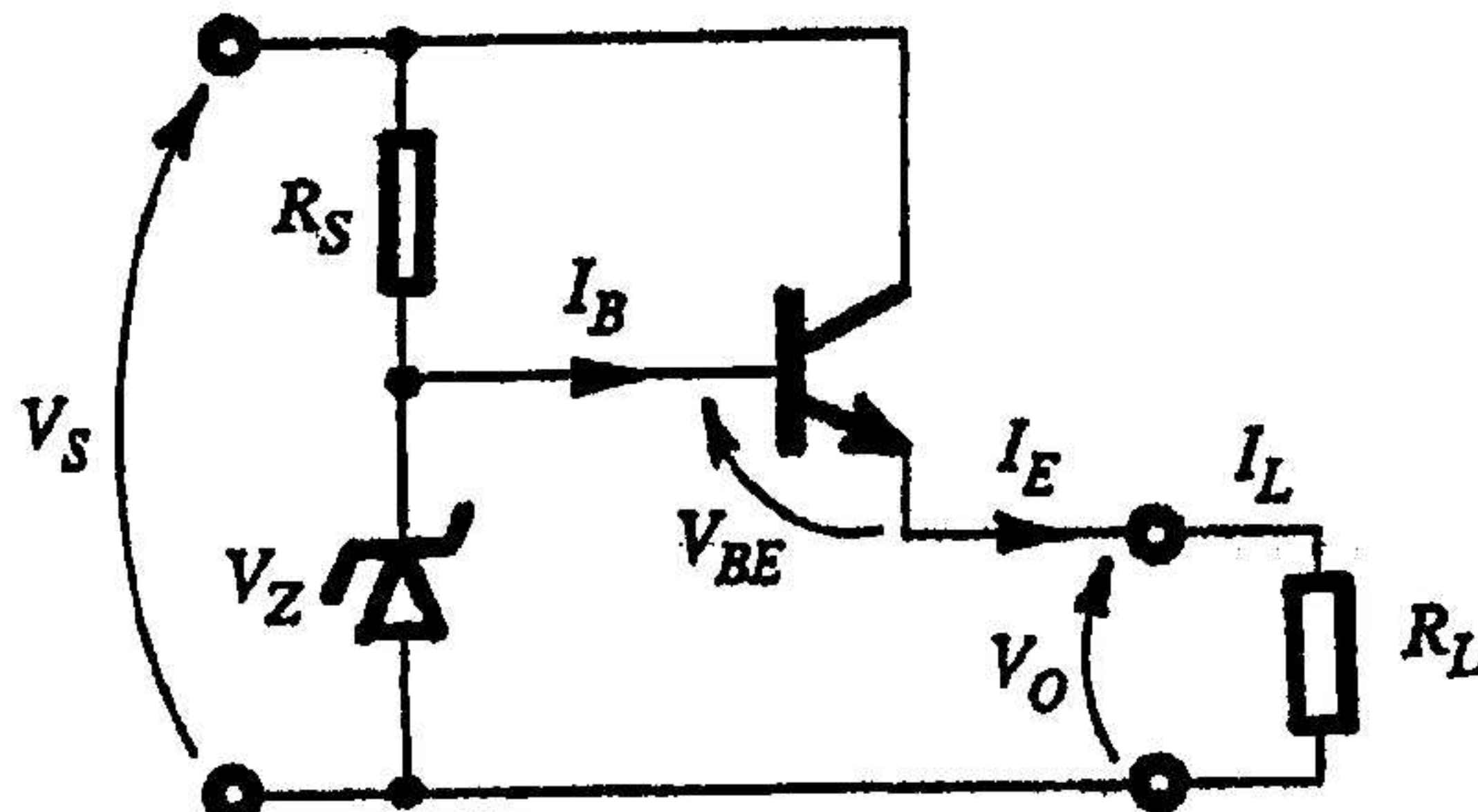
$$= 4 \times \frac{50000}{300000}$$

$$= 0,66 V$$

(4)

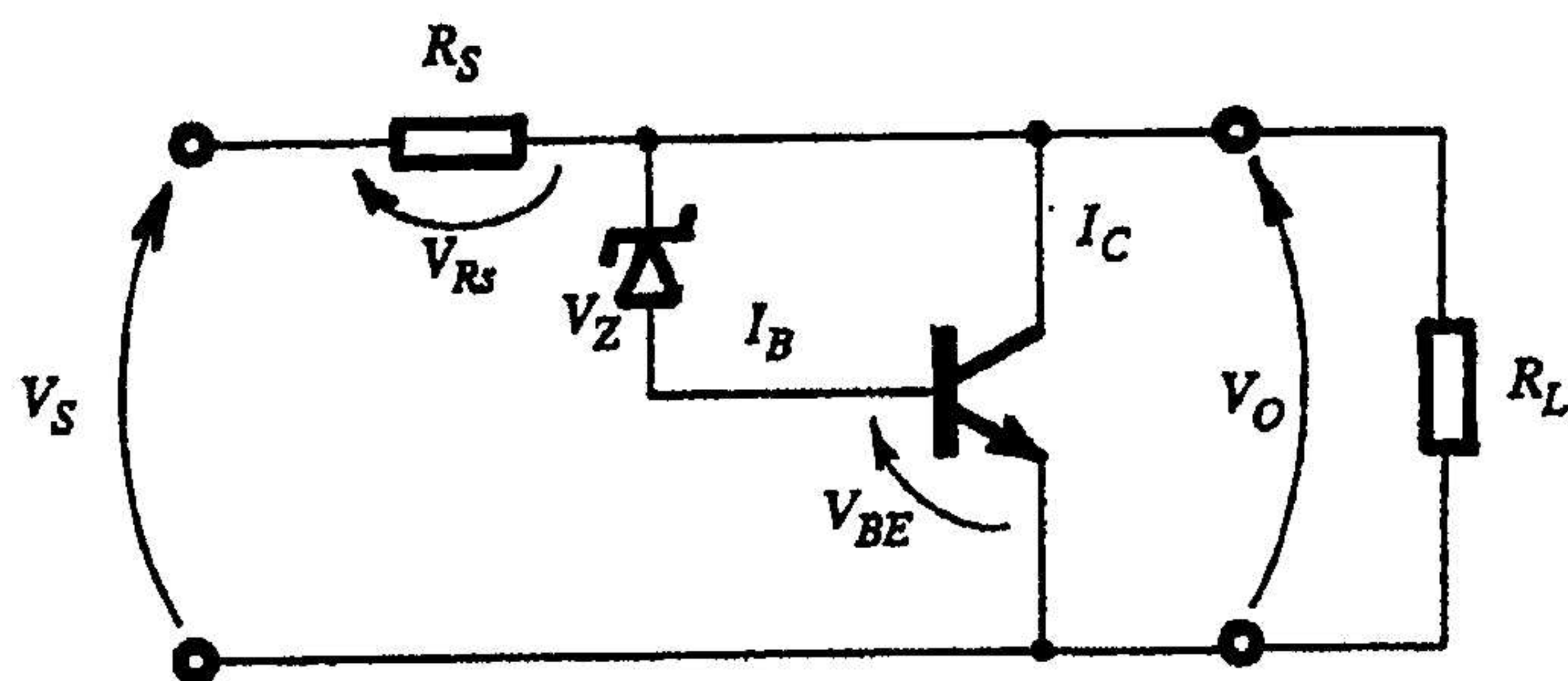
QUESTION 4 / VRAAG 4

4.1 Series voltage regulator



SHUNT VOLTAGE REGULATOR

In this circuit the transistor is placed across the output terminals in parallel with the load.

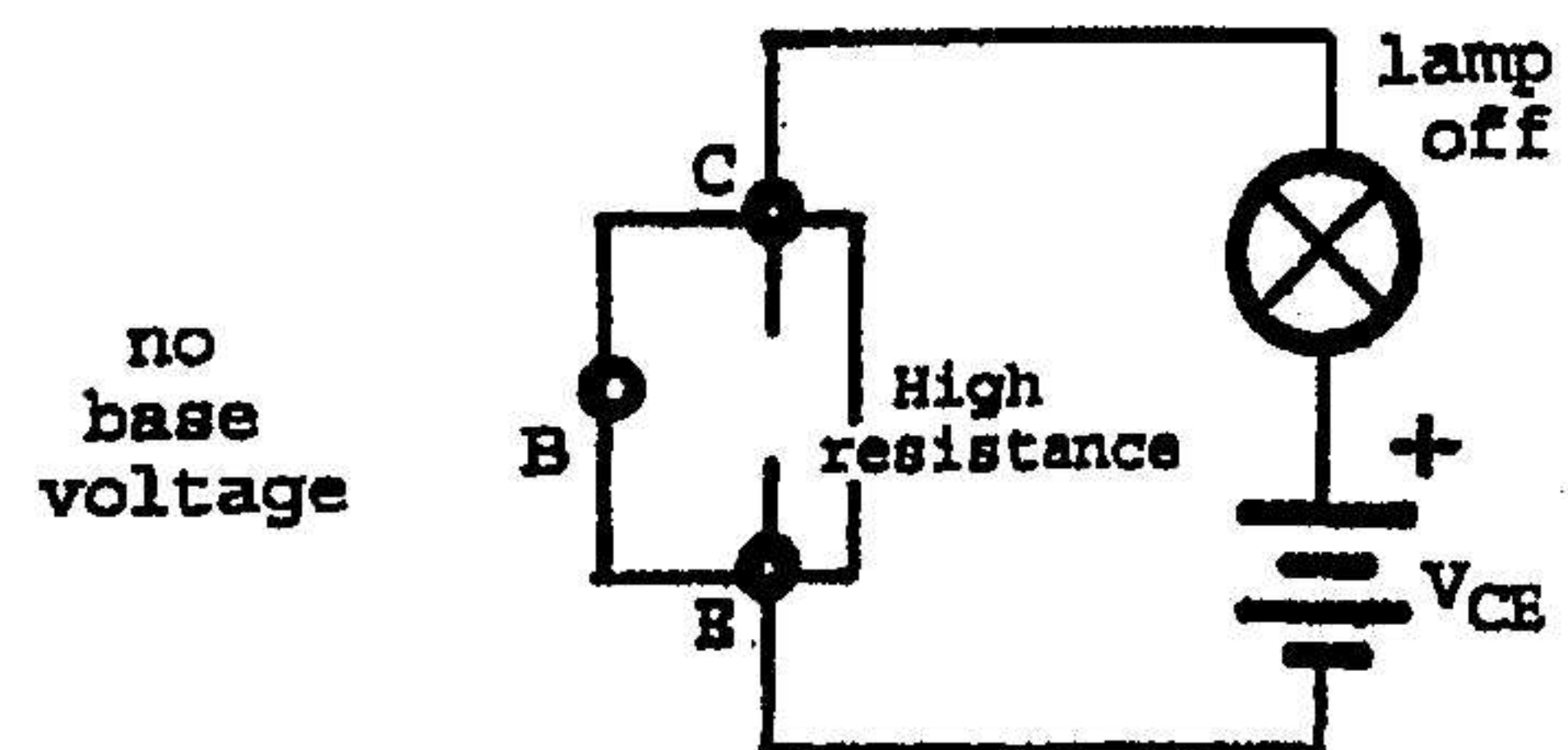


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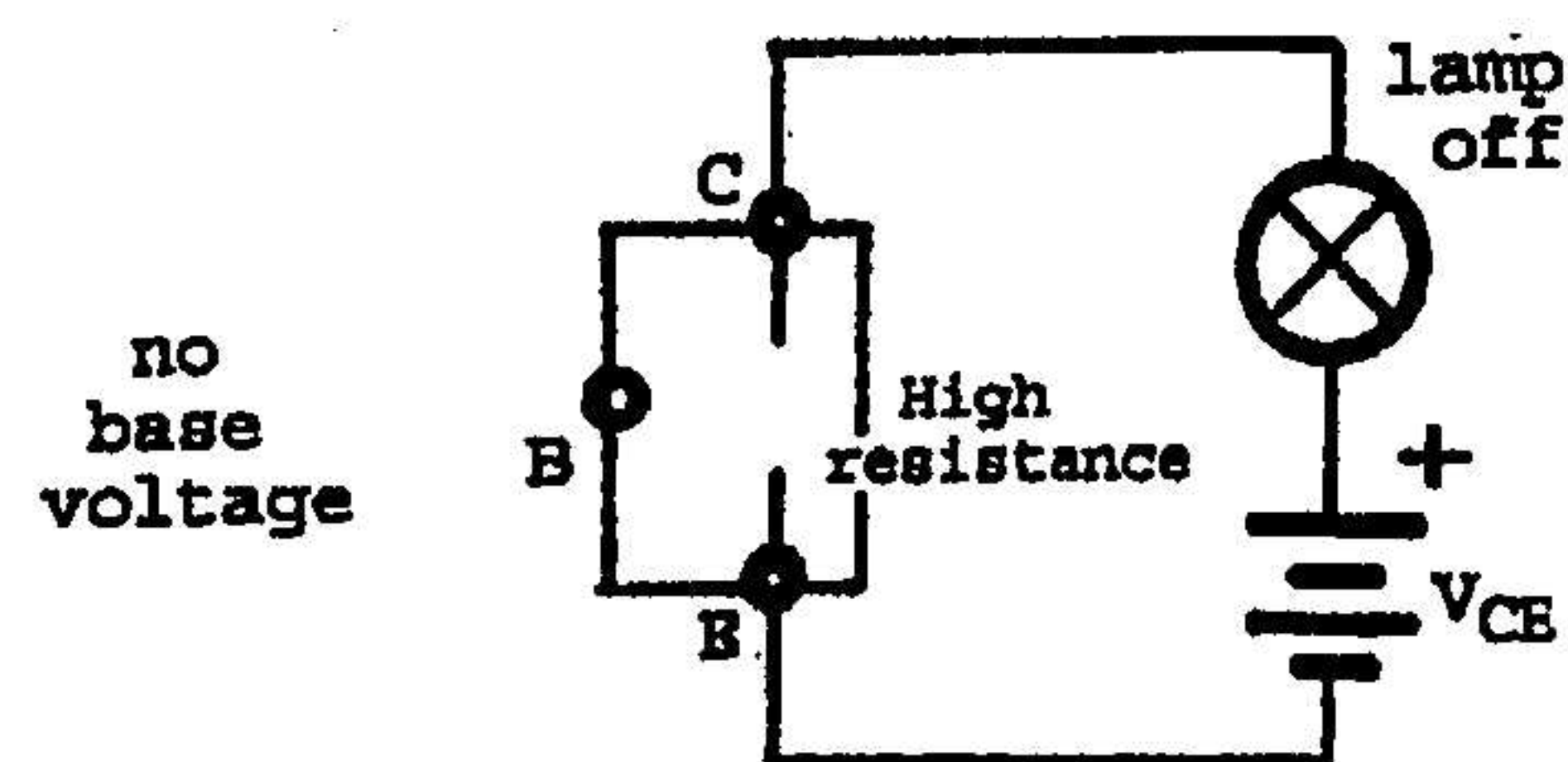
4.2 THE TRANSISTOR OPERATING AS A VARIABLE RESISTOR

If the transistor is viewed as a variable resistor connected in series with a load (here a lamp), the biasing of the emitter-base becomes important.

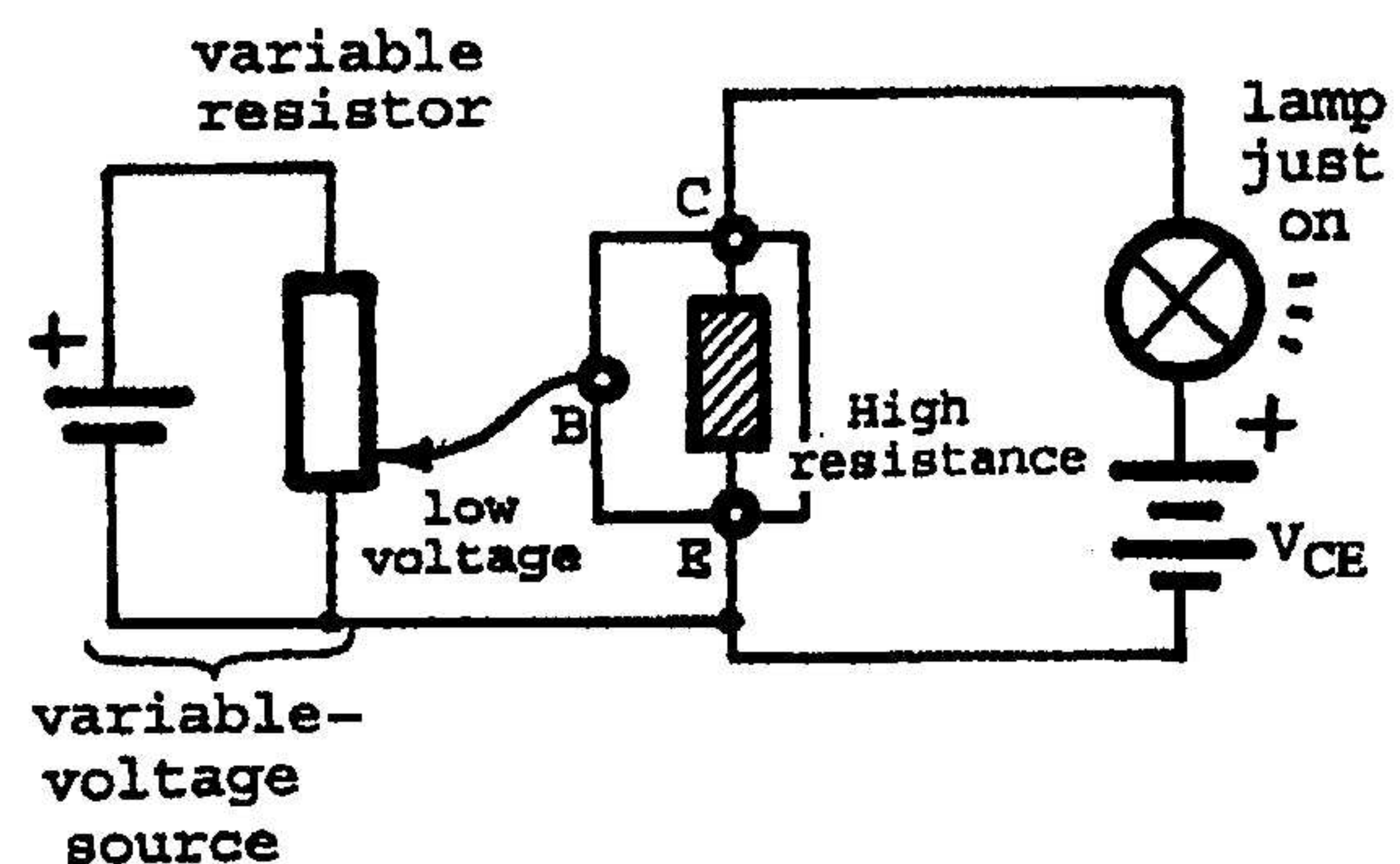
With no emitter-base biasing voltage the e-b junction remains reversed and there is no current flow through the transistor. The transistor appears as a high resistance and the lamp remains "off".



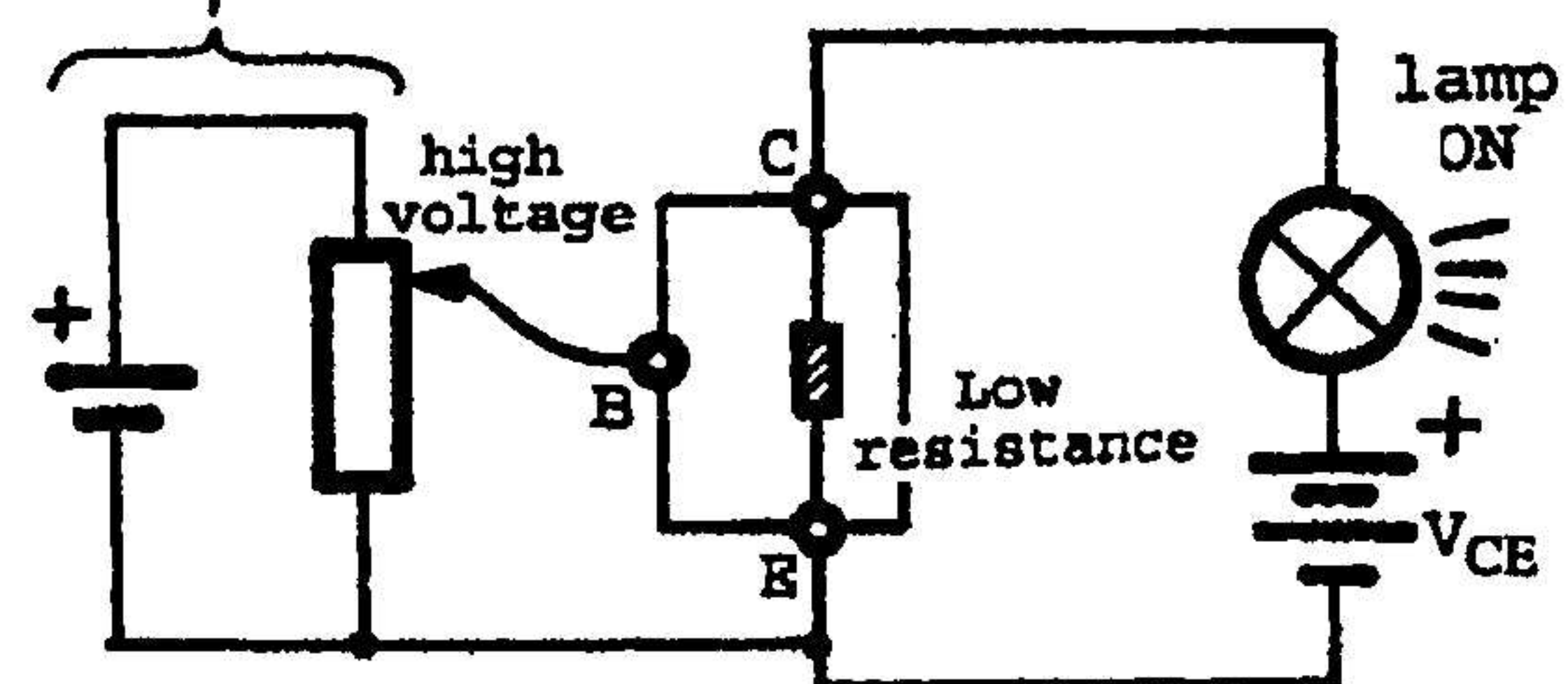
With an emitter-base biasing voltage added, the e-b junction becomes conductive and the transistor begins to conduct. It appears as a **low resistance** allowing current to flow through the collector and the lamp, turning it "on".



If the emitter-base voltage was made variable, then by **reducing** this voltage the e-b junction would slowly shut down making the transistor appear as an **increasing resistance**. The brightness of the lamp reduces as there would be less collector current flowing.



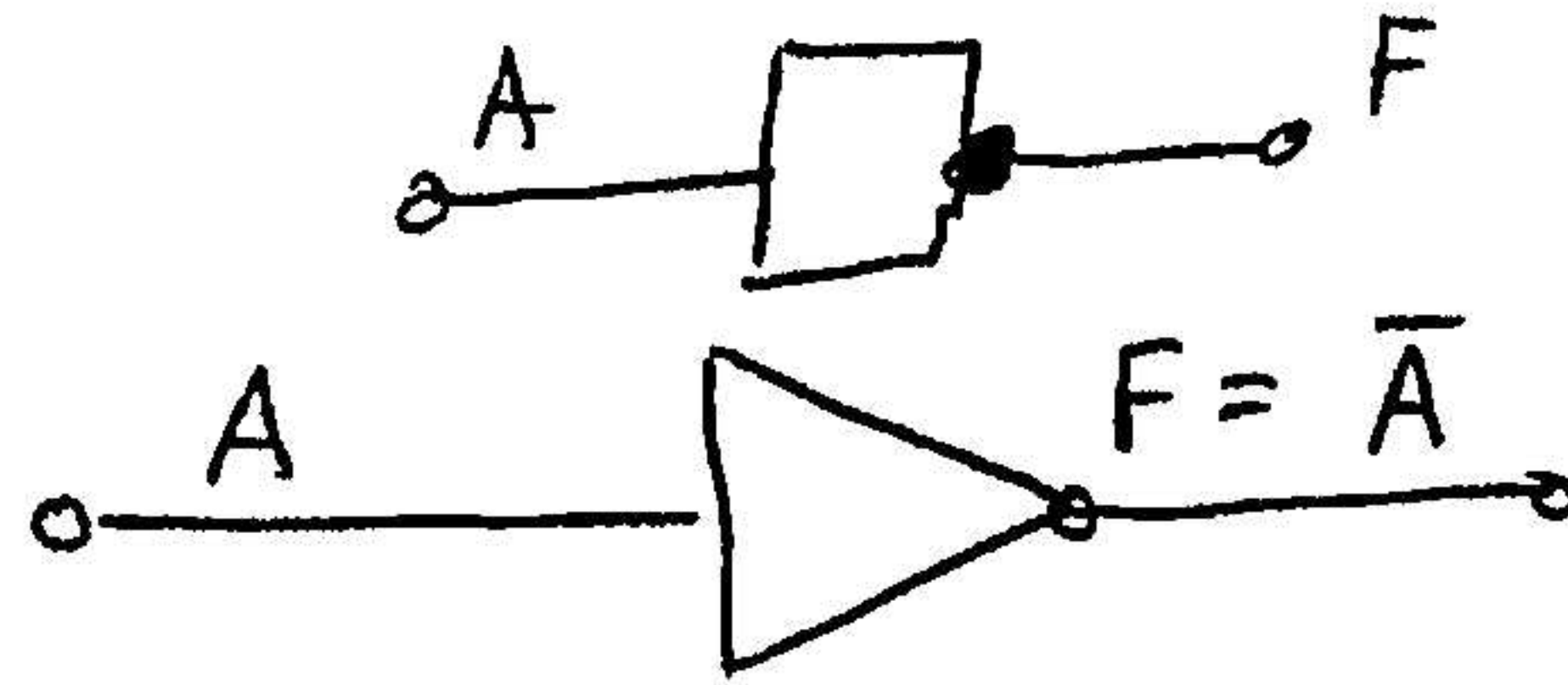
And as the emitter-base biasing voltage was **increased**, more collector current would flow, making the transistor appear as a **decreasing resistance** to current flow, turning the lamp on to its full brightness.



This shows the extent to which the emitter-base biasing circuit has control over the collector circuit's current. It also shows how, by changing this emitter-base voltage, it affects the transistor current flow to make it appear as a "variable resistor".

(12)

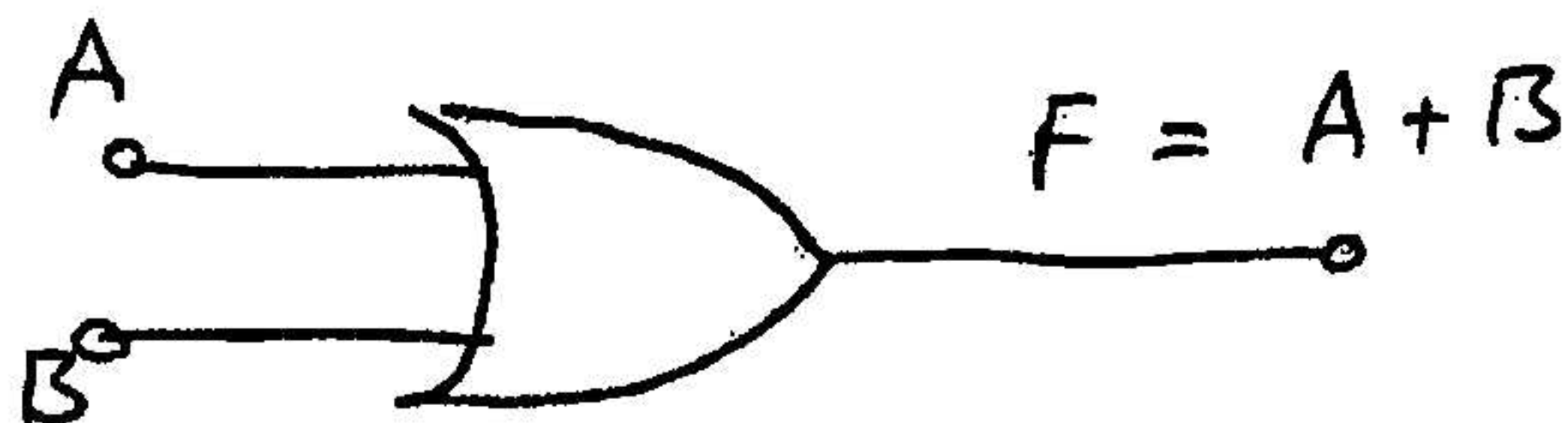
5.1.1



A	\bar{A}
0	1
1	0

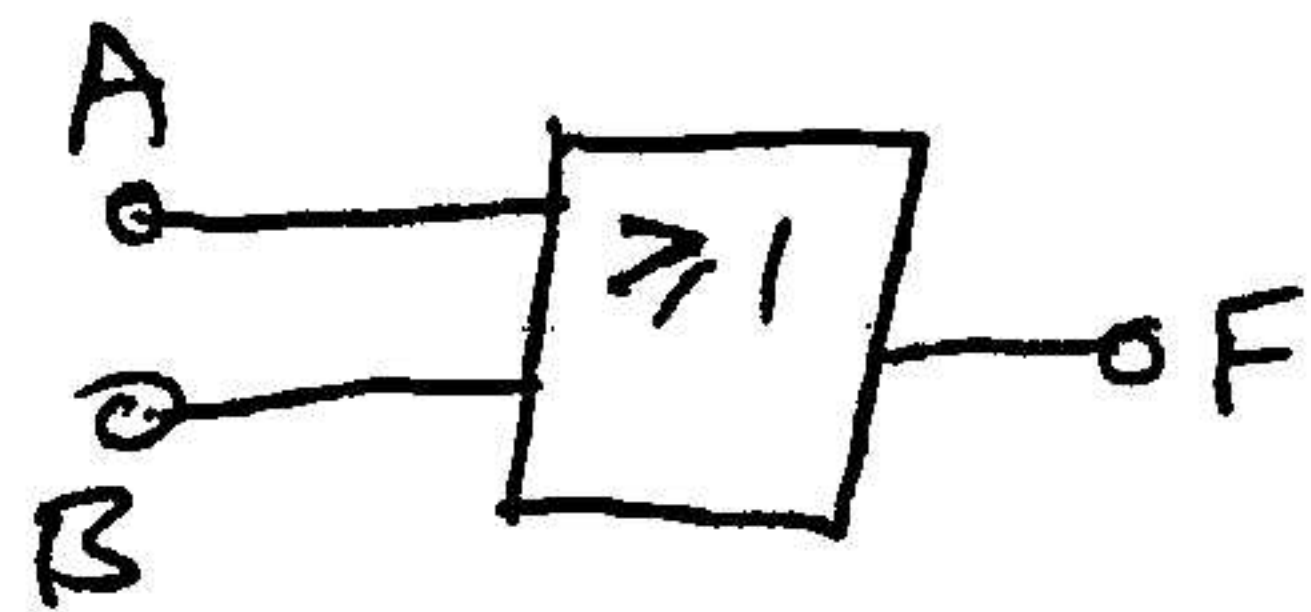
(4)

5.1.2



A	B	F
0	0	0
0	1	1
1	0	1
1	1	1

(6)



5.1.3

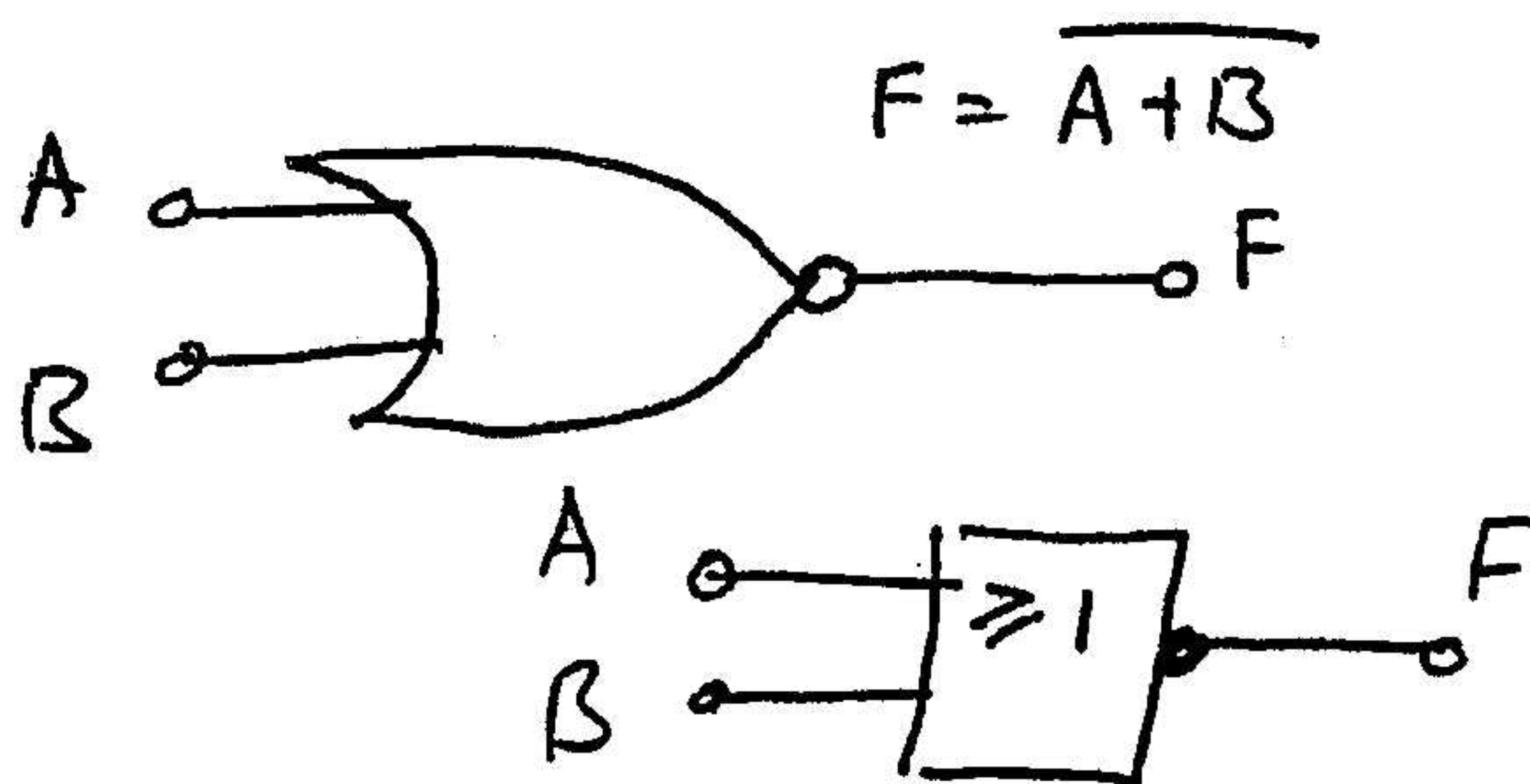


A	B	F
0	0	0
0	1	0
1	0	0
1	1	1

(6)



5.1.4



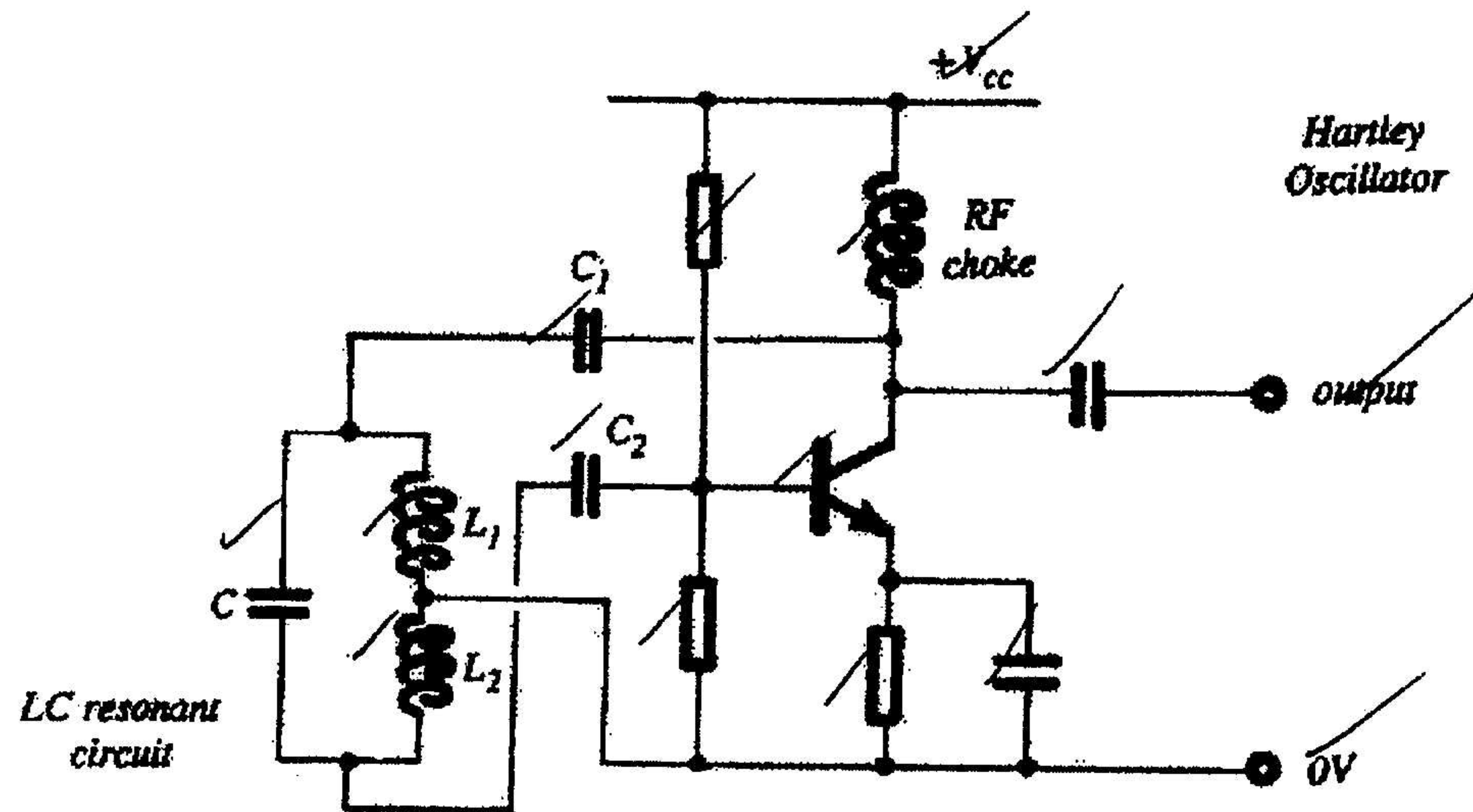
A	B	F
0	0	1
0	1	0
1	0	0
1	1	0

(6)

5.2 $A + B(A \cdot \bar{B}) = A$
 $A + AB \cdot \bar{B} = A$
 $A + 0 = A$
 $A = A$

(10)

QUESTION 6 / VRAAG 6



(15)

QUESTION 7 / VRAAG 7

$$7.1 \quad \text{Time} = 5 \text{ cm} \times 100 \mu\text{s} \\ = 500 \mu\text{s}$$

$$f = \frac{1}{\text{time}} \\ = \frac{1}{500 \times 10^{-6}} \\ = 2000 \text{ Hz} = 2 \text{ kHz}$$

(7)

$$7.2 \quad E_m = 3.2 \text{ cm} \times 10\text{V} \\ = 32 \text{ V}$$

$$\text{Rms} = E_m \times 0,707 \\ = 32 \times 0,707 \\ = 22,62 \text{ V}$$

(6)

QUESTION 8 / VRAAG 8

- 8.1 *
- * *Verseker dat alle draagbare toerusting buigsame kernbedrading het.*
 - * *Alle verbindingspunte moet meganies en elektries korrek wees.*
 - * *Isolasie moet in goeie toestand wees en aan regulasies voldoen*
 - * *Verseker dat die gronddraad die regte kleur is.*
 - * *Verseker dat die gronddraad goeie kontak maak met die metaaldele van die apparaat*
 - * *Koppel die regte kleure op die regte plekke:*

(5)

- (E) Grond = groen en geel
- (N) Neutraal = blou
- (L) Lewendig = bruin.

- 8.2 * Do not work without permission.
* Do not work at unsafe speeds.
* Do not place objects in dangerous places.
* Do not work with the wrong tools.
* Do not wear loose clothing.
* Do not play in the workshop. (5)

- 8.3 *By ingange*
By stoorkamers
By plekke waar daar 'n brandgevaar kan wees
By gasstoorplek (3)

TOTAL / TOTAAL 200